

### **Description**

The AU2481D1F-T is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power lines. The AU2481D1F-T complies with the IEC 61000-4-2 (ESD) with  $\pm$  30kV air and  $\pm$  30kV contact discharge. It is assembled into a SOD-123FL lead-free package. The small size and high ESD/surge protection make AU2481D1F-T an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

### **Features**

- Protects one data or power line
- Ultra low leakage: nA level
- Operating voltage: 24V
- Ultra low clamping voltage
- Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test
    Air discharge: ±30kV
    Contact discharge: ±30kV
  - IEC61000-4-5 (Lightning) 170A (8/20µs)
- RoHS Compliant

### **Mechanical Characteristics**

- Package: SOD-123FL
- Lead Finish: Matte Tin
- Case Material: "Green" Molding Compound.
- Terminal Connections: See Diagram Below
- Marking Information: See Below

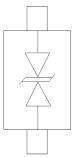
### **Applications**

- Fast-charge battery chargers
- Power management system
- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- Digital Cameras
- Peripherals

### **Marking Information**



# Pin Configuration



## **Ordering Information**

Part Number	Packaging	Reel Size	
AU2481D1F-T	3000/Tape & Reel	7 inch	

#### Circuit and Pin Schematic



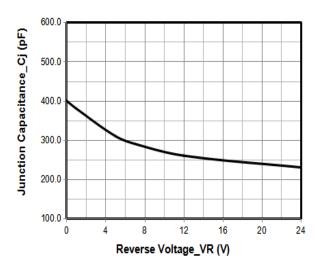
# Absolute Maximum Ratings (T<sub>A</sub>=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ppk	5000	W
Peak Pulse Current (8/20µs)	lpp	170	А
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	VESD	±30 ±30	kV
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	−55 to +150	°C

## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise specified)

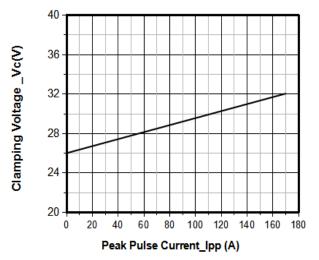
Parameter	Symbol	Min	Тур	Мах	Unit	Test Condition
Reverse Working Voltage	VRWM			24	V	
Breakdown Voltage	VBR	25.0			V	IT = 1mA
Reverse Leakage Current	I <sub>R</sub>			1.0	μA	VRWM = 24V
Forward Voltage	VF		0.73	1.2	V	IF = 10mA
Clamping Voltage	Vc			32	V	IPP = 170A (8 x 20µs pulse)
Junction Capacitance	Сл		400		pF	VR = 0V, f = 1MHz



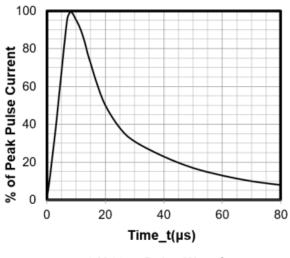


### Typical Performance Characteristics (TA=25°C unless otherwise Specified)

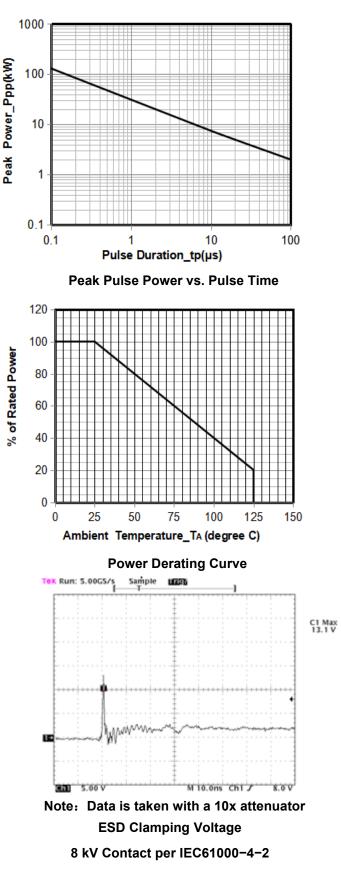
Junction Capacitance vs. Reverse Voltage



**Clamping Voltage vs. Peak Pulse Current** 

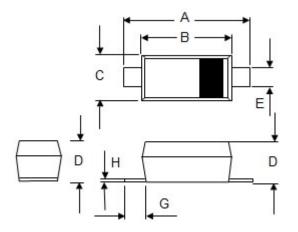


8 X 20µs Pulse Waveform



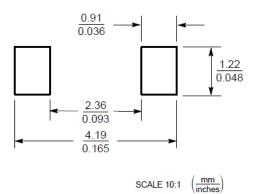


## SOD-123FL Package Outline Drawing



	DIMENSIONS							
	MILLIN	<b>IETERS</b>	INCHES					
SYM	MIN	MAX	MIN	MAX				
А	3.40	3.95	0.142	0.155				
В	2.50	2.90	0.098	0.114				
С	1.40	1.95	0.055	0.077				
D	0.80	1.00	0.031	0.040				
E	0.50	1.10	0.020	0.043				
G	0.25	— -	0.010	— <b>-</b>				
Н	— -	0.20	— <b>-</b>	0.008				

## Suggested Land Pattern



### **Contact Information**

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